

Silicon NPN Power Transistors

2SD1263 2SD1263A

DESCRIPTION

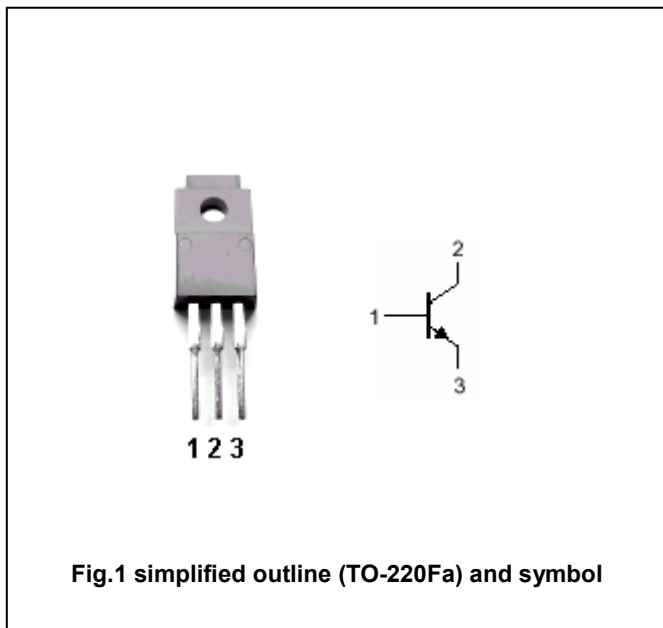
- With TO-220Fa package
- High breakdown voltage

APPLICATIONS

- For power amplification

PINNING

PIN	DESCRIPTION
1	Base
2	Collector
3	Emitter



Absolute maximum ratings(Ta=25°C)

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
V _{CBO}	Collector-base voltage	2SD1263	350	V
		2SD1263A	400	
V _{CEO}	Collector-emitter voltage	2SD1263	250	V
		2SD1263A	300	
V _{EBO}	Emitter-base voltage	Open collector	5	V
I _C	Collector current		0.75	A
I _{CM}	Collector current-peak		1.5	A
P _C	Collector power dissipation	T _a =25°C	2	W
		T _C =25°C	35	
T _j	Junction temperature		150	°C
T _{stg}	Storage temperature		-55~150	°C

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CHARACTERISTICS

T_j=25 °C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT	
V _{CEO}	Collector-emitter voltage	2SD1263	I _C =30mA, I _B =0	250			V
		2SD1263A		300			
V _{CEsat}	Collector-emitter saturation voltage	I _C =1A, I _B =0.2A			1.0	V	
V _{BE}	Base-emitter voltage	I _C =1A; V _{CE} =10V			1.5	V	
I _{EBO}	Emitter cut-off current	V _{EB} =5V; I _C =0			1.0	mA	
I _{CEO}	Collector cut-off current	2SD1263	V _{CE} =150V; I _B =0			1.0	mA
		2SD1263A	V _{CE} =200V; I _B =0			1.0	mA
I _{CES}	Collector cut-off current	2SD1263	V _{CE} =350V; V _{BE} =0			1.0	mA
		2SD1263A	V _{CE} =400V; V _{BE} =0			1.0	mA
h _{FE-1}	DC current gain	I _C =0.3A; V _{CE} =10V	70		250		
h _{FE-2}	DC current gain	I _C =1A; V _{CE} =10V	10				
f _T	Transition frequency	I _C =0.5A; V _{CE} =5V, f=10MHz		30		MHz	

Switching times

t _{on}	Turn-on time	I _C =1A; I _{B1} =-I _{B2} =0.1A V _{CC} =50V		0.5		μs
t _s	Storage time			2		μs
t _f	Fall time			0.5		μs

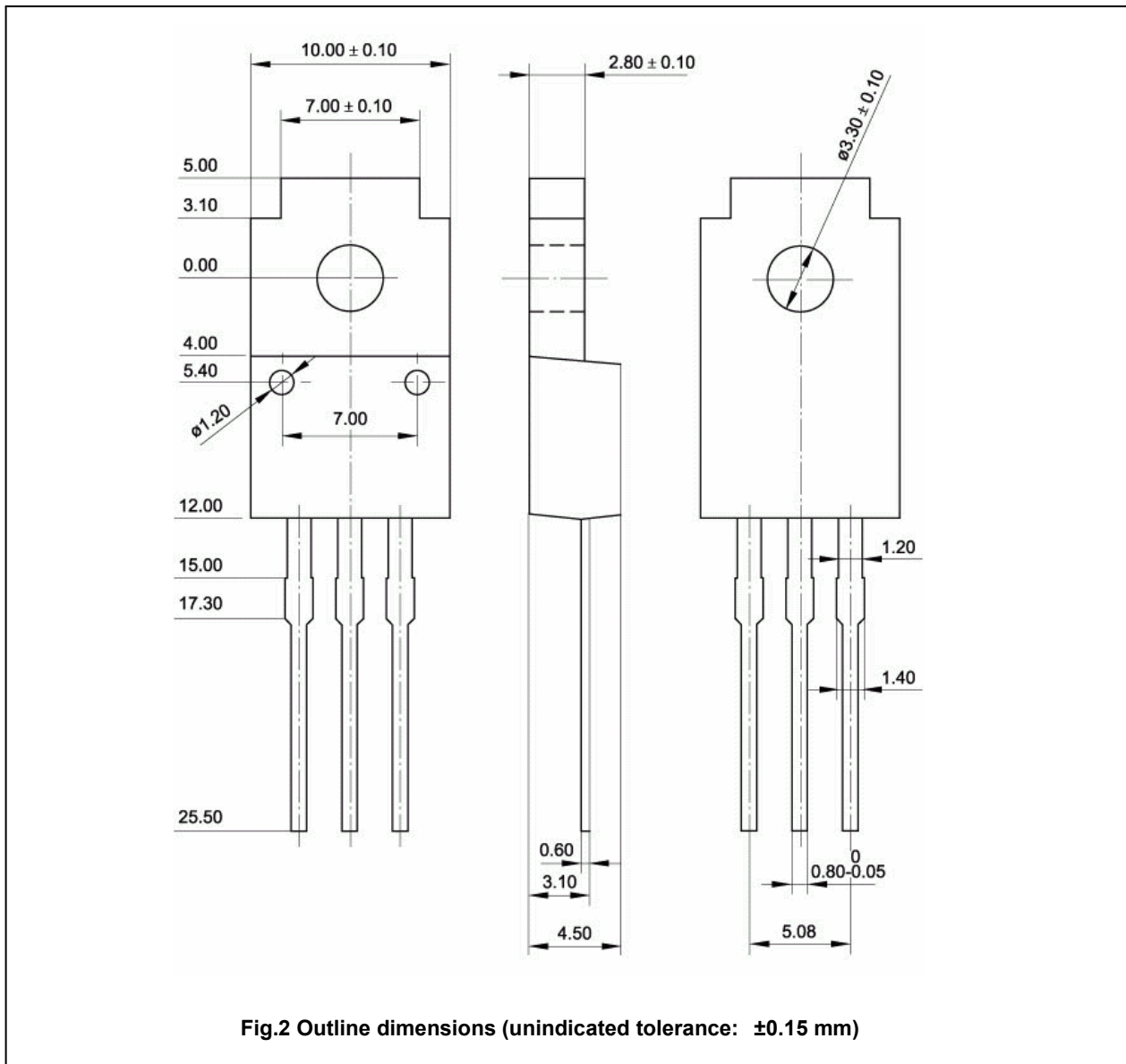
◆ h_{FE-1} Classifications

Q	P
70-150	120-250

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PACKAGE OUTLINE



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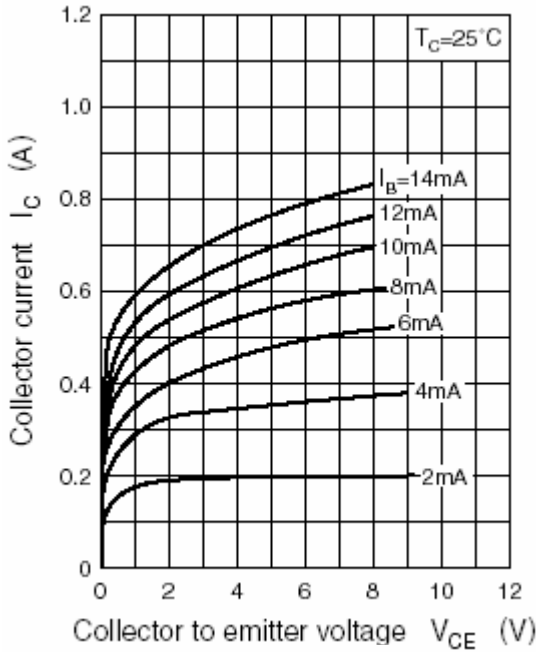


Fig.3 Static Characteristic

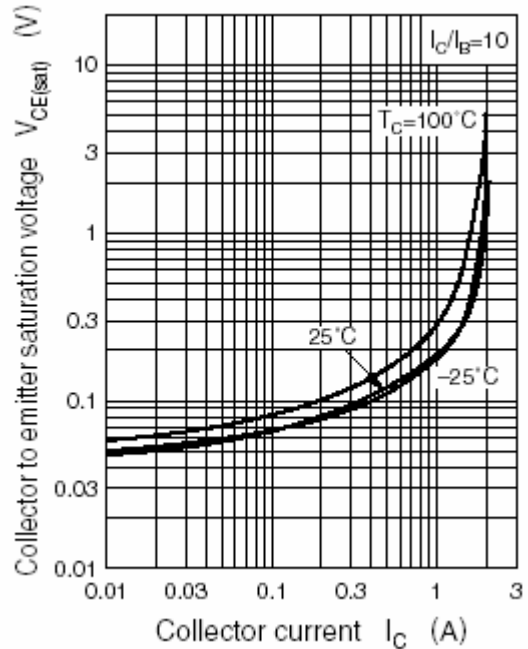


Fig.4 Collector-Emitter Saturation Voltage

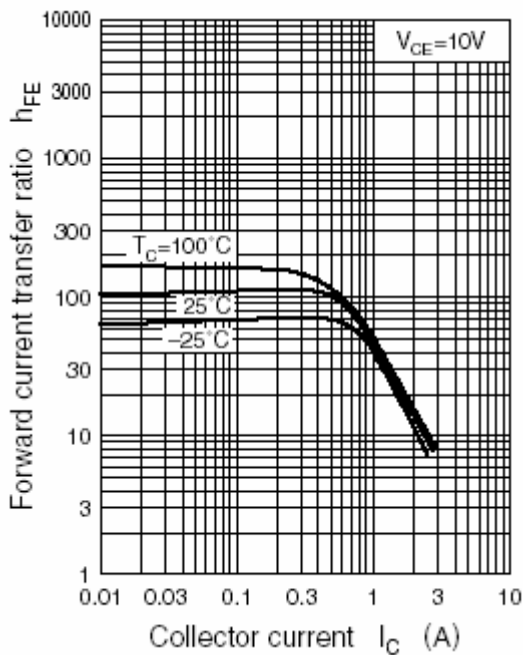


Fig.5 DC current Gain

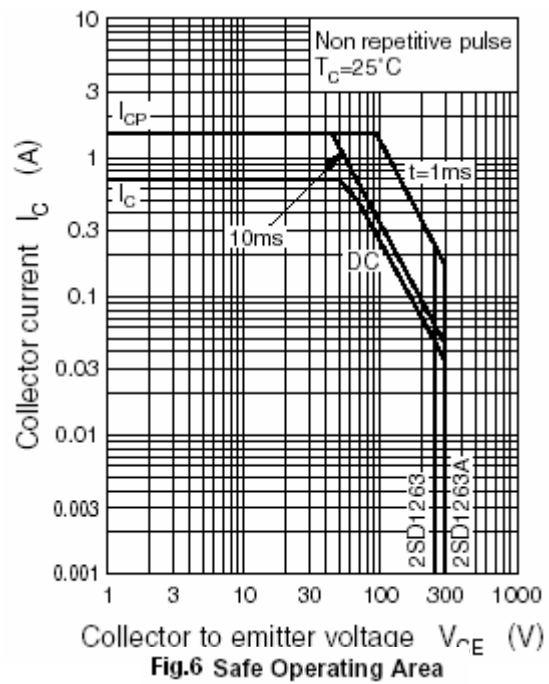


Fig.6 Safe Operating Area